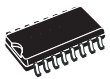
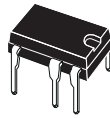


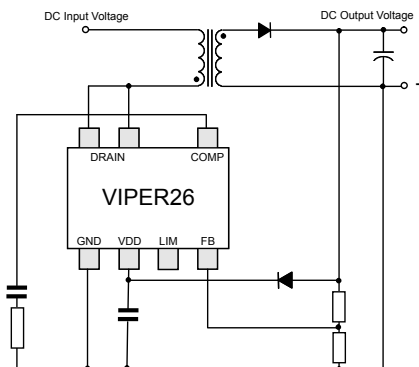
## Fixed frequency VIPer plus family



SO16 narrow



DIP-7



## Features

- 800 V avalanche rugged power MOSFET allowing wide range  $V_{AC}$  input range to be covered
- Embedded HV startup and sense-FET
- Current mode PWM controller
- Minimized system input power consumption:
  - Less than 30 mW @ 230 V<sub>AC</sub> in no-load condition
  - Less than 400 mW @ 230 V<sub>AC</sub> with 250 mW load
- Limiting current with adjustable set point
- Jittered switching frequency to reduce the EMI filter cost:
  - 60 kHz  $\pm$ 4 kHz (L type)
  - 115 kHz  $\pm$ 8 kHz (H type)
- Embedded error amplifier
- Hysteretic thermal shutdown
- Built-in soft-start for improved system reliability
- Protections with automatic restart: overload/short-circuit (OLP), feedback loop disconnection

## Application

- Auxiliary power supply for appliances
- Power metering
- LED drivers
- SMPS for set-top boxes, DVD players and recorders

## Product status link

[VIPER26](#)

## Product label



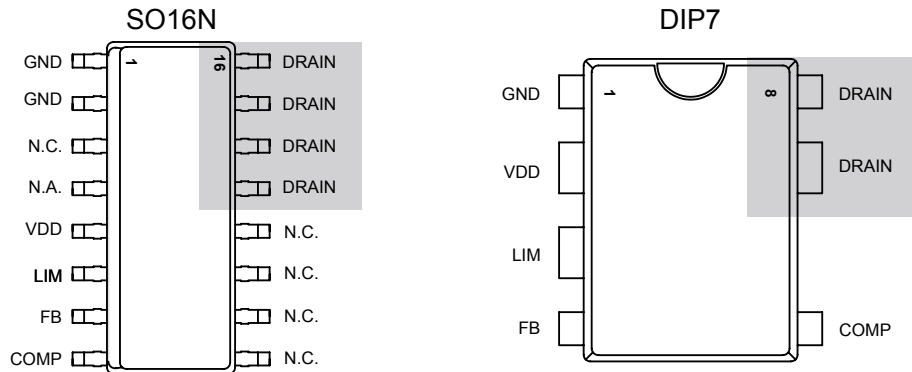
## Description

The VIPER26 device is a smart high voltage converter that integrates an 800 V avalanche-rugged power MOSFET with PWM current mode control. The power MOSFET with 800 V breakdown voltage allows an extended input voltage range to be applied, as well as the size of the DRAIN snubber circuit to be reduced.

This IC meets the most stringent energy-saving standards with very low consumption and burst mode operation under light load.

The design of flyback, buck and buck boost converters is supported. The integrated HV startup, sense-FET, error amplifier and oscillator with jitter allow complete application designs with a minimum number of components.

# 1 Pin settings

**Figure 1. Connection diagram (top view)**


*Note:* The copper area for heat dissipation has to be designed under the DRAIN pins.

**Table 1. Pin descriptions**

Pin number		Name	Function
DIP7	SO16N		
1	1-2	GND	<b>Ground and MOSFET source.</b> Connection of the source of the internal MOSFET and controller ground reference.
-	3	N.C.	<b>Not connected.</b> This pin can be soldered to GND.
-	4	N. A.	<b>Not available for user.</b> This pin is mechanically connected to the controller die pad of the frame. In order to improve noise immunity, it is highly recommended to connect it to GND (pin 1,2).
2	5	VDD	<b>Controller Supply.</b> An external storage capacitor has to be connected across this pin and GND. The pin, internally connected to the high voltage current source, provides the VDD capacitor charging current at startup and during fault conditions. A small bypass capacitor (0.1 $\mu$ F typ.) in parallel, placed as close as possible to the IC, is also recommended for noise filtering purposes.
3	6	LIM	<b>Drain current limitation.</b> This pin allows setting the drain current limitation to a lower value than the default $I_{Dlim}$ value. The limit can be reduced by connecting an external resistor between this pin and GND. In case of high electrical noise, a capacitor may be connected between this pin and GND; the capacitor value must be lower than 470 nF in order to not impact the functionality of the pin. The pin can be left open if the default drain current limitation, $I_{Dlim}$ , is used.
4	7	FB	<b>Direct feedback.</b> It is the inverting input of the internal transconductance E/A, which is internally referenced to 3.3 V with respect to GND. In a non-isolated converter, the output voltage information is directly fed into the pin through a voltage divider. In primary regulation, the FB voltage divider is connected to the VCC. The E/A is disabled by soldering FB to GND.
5	8	COMP	<b>Compensation.</b> It is the output of the internal E/A. A compensation network is placed between this pin and GND to achieve stability and good dynamic performance of the control loop. In case of isolated secondary side regulation, the internal E/A must be disabled and the COMP directly driven by the optocoupler to control the DRAIN peak current setpoint.
-	9-12	N.C.	<b>Not internally connected.</b> These pins must be left floating in order to ensure a safe clearance distance.
7,8	13-16	DRAIN	<b>MOSFET drain.</b> The internal high voltage current source sinks current from this pin to charge the VCC capacitor at startup. These pins are mechanically connected to the internal metal PAD of the MOSFET in order to facilitate heat dissipation. On the PCB, the copper area must be placed under these pins in order to decrease the total junction-to-ambient thermal resistance, thus facilitating the power dissipation.

## 2 Electrical and thermal ratings

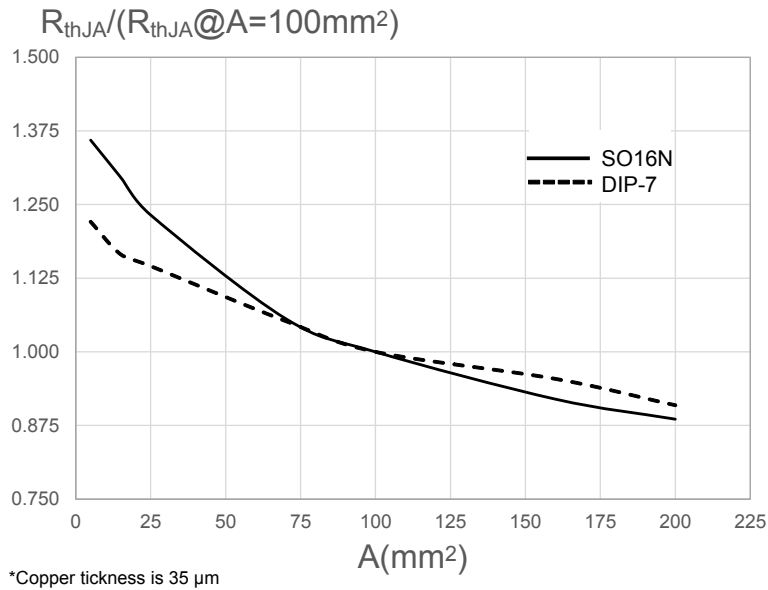
**Table 2. Absolute maximum ratings**

Symbol	Parameter	Min.	Max.	Unit
V <sub>DRAIN</sub>	Drain-to- source (ground) voltage	-	800	V
I <sub>DRAIN</sub>	Pulse drain current (limited by T <sub>J</sub> = 150 °C)	-	3	A
V <sub>COMP</sub>	COMP voltage	-0.3	3.5V	V
V <sub>FB</sub>	FB voltage	-0.3	4.8	V
V <sub>LIM</sub>	LIM voltage	-0.3	2.4	V
V <sub>DD</sub>	Supply voltage	-0.3	Self limited	V
I <sub>DD</sub>	Input current	-0.3	20	mA
P <sub>TOT</sub>	Power Dissipation @ Tamb < 40 °C (DIP7)	-	1	W
	Power Dissipation @ Tamb < 60 °C (SO16N)	-	1.5	W
T <sub>J</sub>	Junction Temperature operating range	-40	150	°C
T <sub>STG</sub>	Storage Temperature	-55	150	°C

**Table 3. Thermal data**

Symbol	Parameter	Max. value		Unit
		SO16N	DIP-7	
R <sub>TH-JC</sub>	Thermal resistance junction to case <sup>(1)</sup> (Dissipated power = 1 W)	10	10	°C/W
R <sub>TH-JA</sub>	Thermal resistance junction ambient <sup>(1)</sup> (Dissipated power = 1 W)	120	120	°C/W
R <sub>TH-JC</sub>	Thermal resistance junction to case <sup>(2)</sup> (Dissipated power = 1 W)	5	5	°C/W
R <sub>TH-JA</sub>	Thermal resistance junction ambient <sup>(2)</sup> (Dissipated power = 1 W)	85	95	°C/W

1. When mounted on a standard, single side FR4 board with minimum copper area.
2. When mounted on a standard, single side FR4 board with 100 mm<sup>2</sup> of Cu (35 μm thick).

**Figure 2.  $R_{th}$  versus area**

**Table 4. Avalanche characteristics**

Symbol	Parameter	Min.	Max.	Unit
$E_{AV}$	Repetitive avalanche energy (limited by $T_J=150^\circ\text{C}$ )	-	5	mJ
$I_{AR}$	Repetitive avalanche current (limited by $T_J=150^\circ\text{C}$ )	-	1.5	A

## 2.1 Electrical characteristics

$T_J = -40$  to  $125^\circ\text{C}$ ,  $V_{DD} = 14$  V (unless otherwise specified)

*Note:* Adjust  $V_{DD}$  above  $V_{DD}$  on startup threshold before setting to 14 V

**Table 5. Power section**

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
$V_{BVDS}$	Breakdown voltage	$I_{DRAIN} = 1$ mA, $V_{COMP} = V_{GND}$ , $T_J = 25^\circ\text{C}$	800	-	-	V
$I_{OFF}$	OFF state drain current	$V_{DRAIN} = \text{max. rating}$ , $V_{COMP} = V_{GND}$ , $T_J = 25^\circ\text{C}$	-	-	60	$\mu\text{A}$
$R_{DS(on)}$	Static drain-source ON-resistance	$I_{DRAIN} = 0.2$ A, $T_J = 25^\circ\text{C}$	-	-	7	$\Omega$
		$I_{DRAIN} = 0.2$ A, $T_J = 125^\circ\text{C}$	-	-	14	$\Omega$

**Table 6. Supply section**

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
<b>Voltage</b>						
$V_{DRAIN\_START}$	Drain-source start voltage	$I_{DRAIN} = 1$ mA; $V_{COMP} = \text{GND}$ ; $T_J = 25^\circ\text{C}$	-	-	90	V
$I_{DDch1}$	Charging current during startup	$V_{DRAIN} = 100$ to $640$ V; $V_{DD} = 4$ V	-0.6	-	-1.8	mA

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
$I_{DDch2}$	Charging current during autorestart	$V_{DRAIN} = 100$ to $640$ V; $V_{DD} = 9$ V falling edge	-7	-	-13	mA
$V_{DD}$	Operating voltage range	-	11.5	-	23.5	V
$V_{DDclamp}$	$V_{DD}$ clamp voltage	$I_{DD} = 15$ mA;	23.5	-	-	V
$V_{DDon}$	$V_{DD}$ startup threshold	-	12	13	14	V
$V_{DDCSon}$	$V_{DD}$ on internal high voltage current generator threshold	-	9.5	10.5	11.5	V
$V_{DDoff}$	$V_{DD}$ undervoltage shutdown threshold	-	7	8	9	V
<b>Current</b>						
$I_{DD0}$	Operating supply current, not switching	$F_{OSC} = 0$ kHz; $V_{COMP} = GND$	-	-	0.6	mA
$I_{DD1}$	Operating supply current, switching	$V_{DRAIN} = 120$ V; $V_{SW} = 60$ kHz	-	-	2	
		$V_{DRAIN} = 120$ V; $V_{SW} = 115$ kHz	-	-	3	
$I_{DDoff}$	Operating supply current with $V_{DD} < V_{DDoff}$	$V_{DD} < V_{DDoff}$	-	-	0.35	
$I_{DDol}$	Open loop failure current threshold	$V_{DD} = V_{DDclamp}$ ; $V_{COMP} = 3.3$ V	4	-	-	

**Table 7. Controller section**

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
<b>Error amplifier</b>						
$V_{REF\_FB}$	FB reference voltage	-	3.2	3.3	3.4	V
$I_{FB\_PULL\ UP}$	Pull-up current	-	-	-1	-	$\mu$ A
$G_M$	Trans conductance	$V_{COMP} = 1.5$ V, $V_{FB} > V_{FB\ REF}$	-	2	-	mA/V
<b>Current setting (LIM) pin</b>						
$V_{LIM\_LOW}$	Low level clamp voltage	$I_{LIM} = -100$ $\mu$ A	-	0.5	-	V
<b>Compensation (COMP) pin</b>						
$V_{COMPH}$	Upper saturation limit	$T_J = 25^\circ C$	-	3	-	V
$V_{COMPL}$	Burst mode threshold	$T_J = 25^\circ C$	1	1.1	1.2	V
$V_{COMPL\_HYS}$	Burst mode hysteresis	$T_J = 25^\circ C$	-	40	-	mV
$H_{COMP}$	$\Delta V_{COMP}/\Delta I_{DRAIN}$	-	-	3	-	V/A
$R_{COMP(DYN)}$	Dynamic resistance	$V_{FB} = GND$	-	15	-	k $\Omega$
$I_{COMP}$	Source / sink current	$V_{FB} > 100$ mV	-	150	-	$\mu$ A
	Max. source current	$V_{COMP} = GND$ ; $V_{FB} = GND$	-	220	-	
<b>Current limitation</b>						
$I_{DLIM}$	Drain current limitation	$I_{LIM} = -10$ $\mu$ A; $V_{COMP} = 3.3$ V; $T_J = 25^\circ C$	0.66	0.7	0.74	A
$t_{SS}$	Soft-start time	-	-	8.5	-	ms
$t_{ON\_MIN}$	Minimum turn-on time	-	-	-	480	ns
$I_{Dlim\_bm}$	Burst mode current limitation	$V_{COMP} = V_{COMPL}$	-	145	-	mA
<b>Overload</b>						
$t_{OVL}$	Overload time	-	-	50	-	ms

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
$t_{\text{RESTART}}$	Restart time after fault	-	-	1	-	s
<b>Oscillator section</b>						
$F_{\text{OSC}}$	Switching frequency	VIPER26L	54	60	66	kHz
		VIPER26H	103	115	127	
$F_{\text{D}}$	Modulation depth	$F_{\text{OSC}} = 60 \text{ kHz}$	-	$\pm 4$	-	kHz
		$F_{\text{OSC}} = 115 \text{ kHz}$	-	$\pm 8$	-	
$F_{\text{M}}$	Modulation frequency	-	-	230	-	Hz
$D_{\text{MAX}}$	Maximum duty cycle	-	70	-	80	%
<b>Thermal shutdown</b>						
$T_{\text{SD}}$	Thermal shutdown temperature threshold	-	150	160	-	$^{\circ}\text{C}$
$T_{\text{HYS}}$	Thermal shutdown hysteresis	-	-	30	-	$^{\circ}\text{C}$

### 3 Typical electrical characteristics

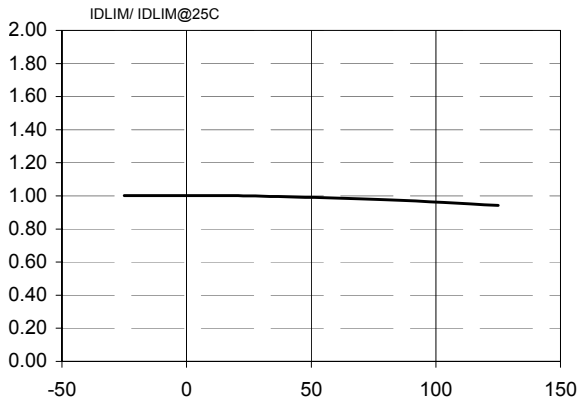
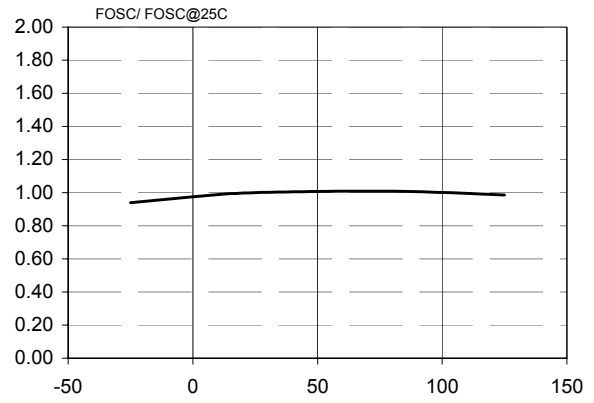
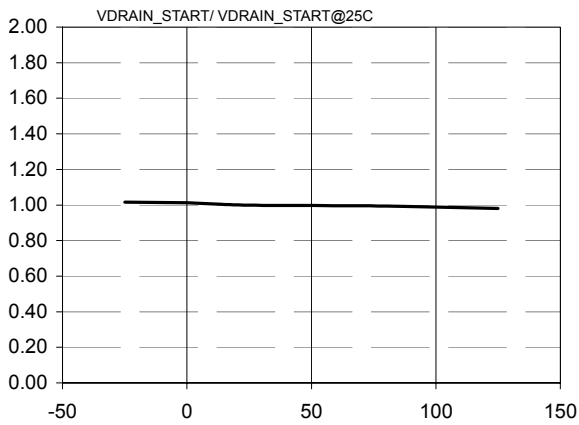
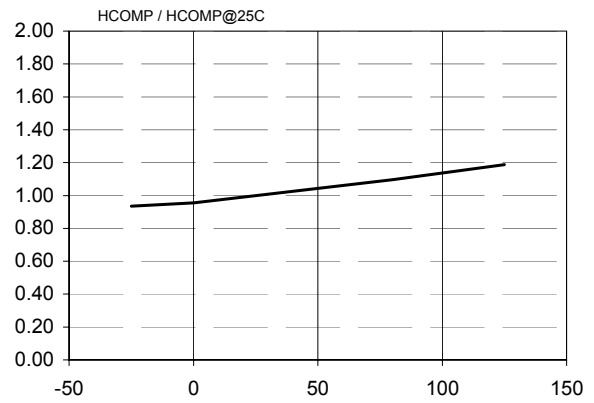
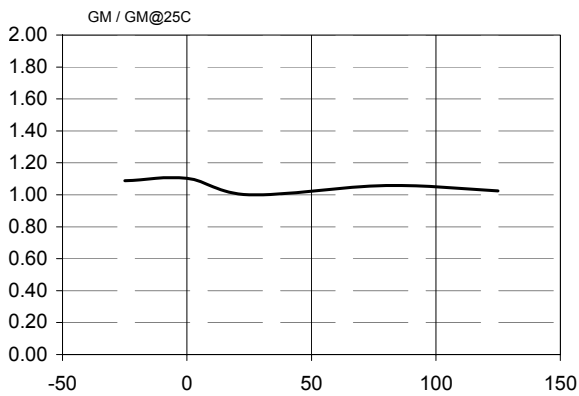
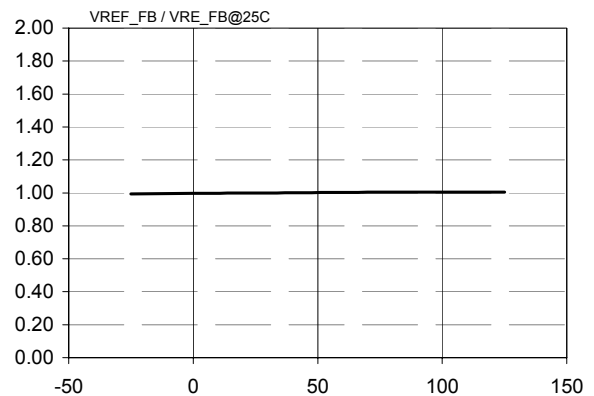
**Figure 3.  $I_{DLIM}$  vs.  $T_J$** 

**Figure 4.  $F_{osc}$  vs.  $T_J$** 

**Figure 5.  $V_{DRAIN\_START}$  vs.  $T_J$** 

**Figure 6.  $H_{COMP}$  vs.  $T_J$** 

**Figure 7.  $G_M$  vs.  $T_J$** 

**Figure 8.  $V_{REF\_FB}$  vs.  $T_J$** 


Figure 9. I<sub>COMP</sub> vs. T<sub>J</sub>

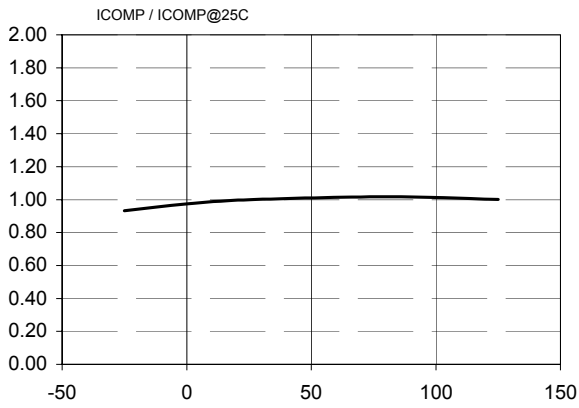


Figure 10. Operating supply current (no switching) vs T<sub>J</sub>

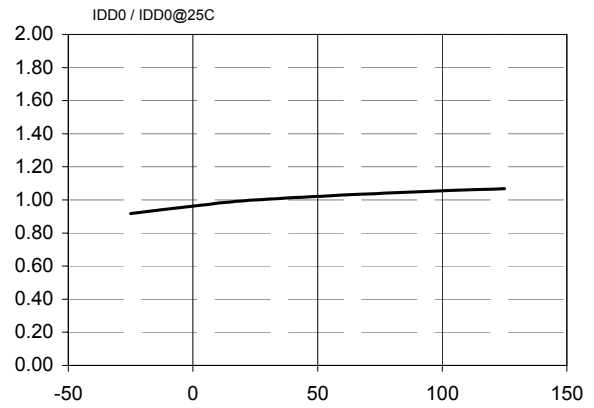


Figure 11. Operating supply current (switching) vs T<sub>J</sub>

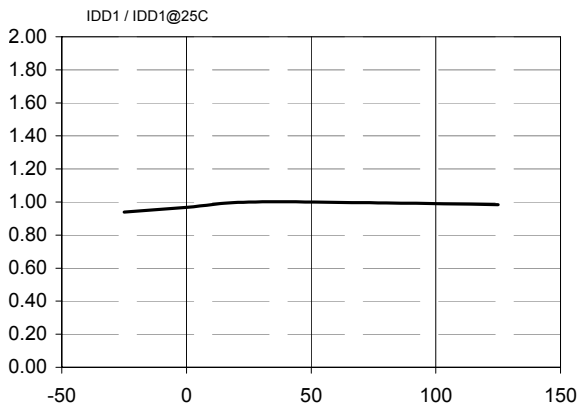


Figure 12. I<sub>DLIM</sub> vs. R<sub>LIM</sub>

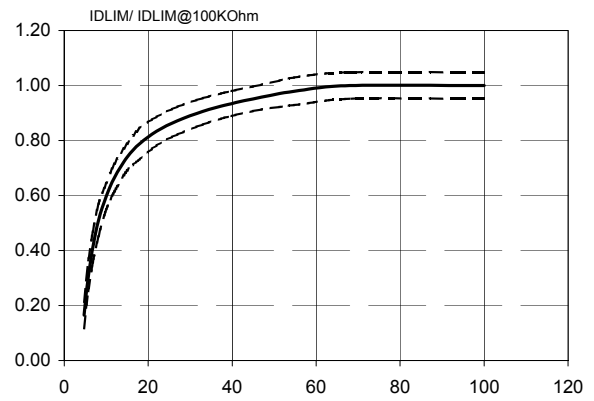


Figure 13. Power MOSFET on-resistance vs T<sub>J</sub>

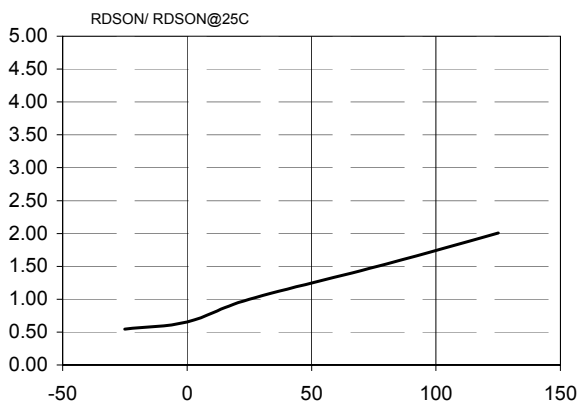
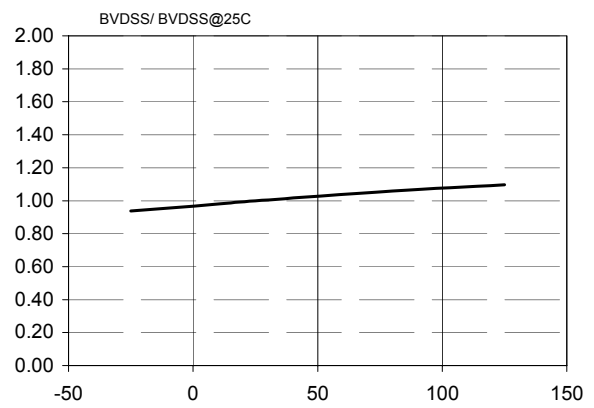
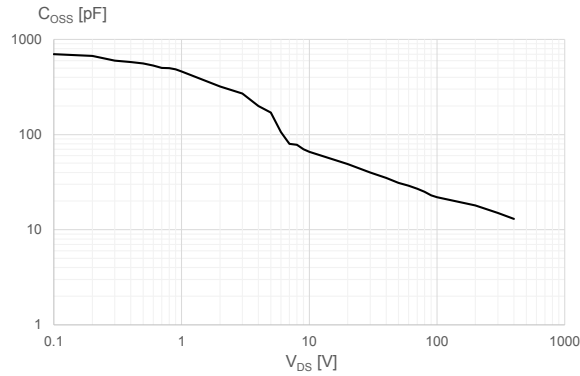
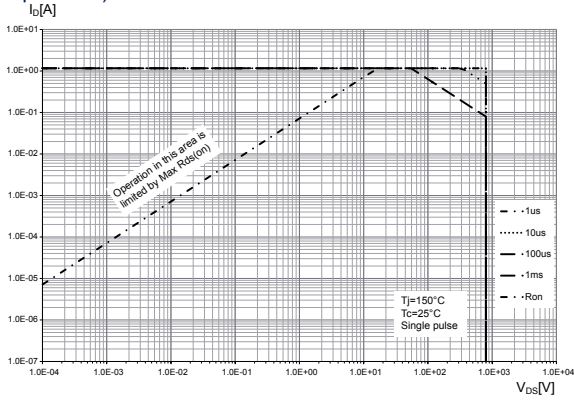


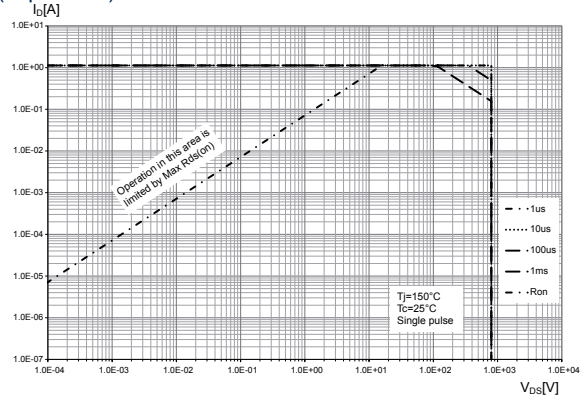
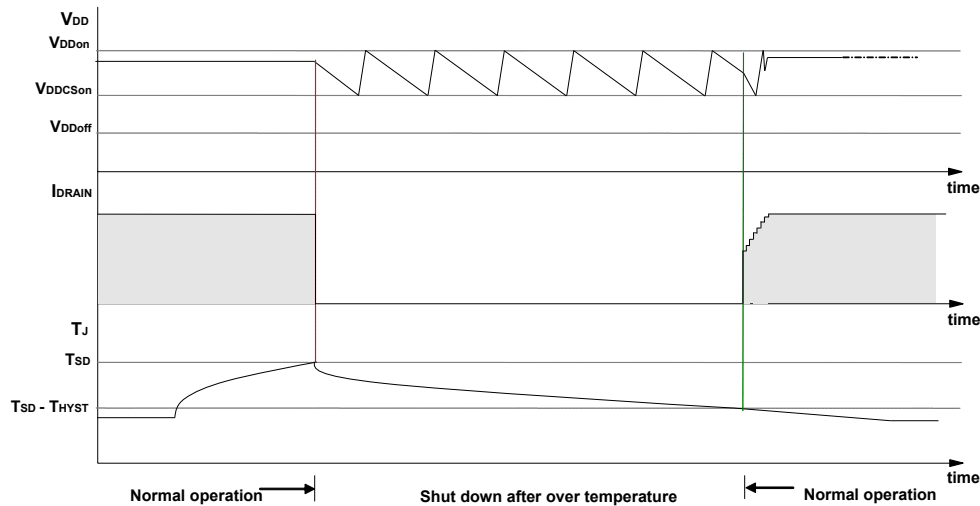
Figure 14. Power MOSFET breakdown voltage vs T<sub>J</sub>



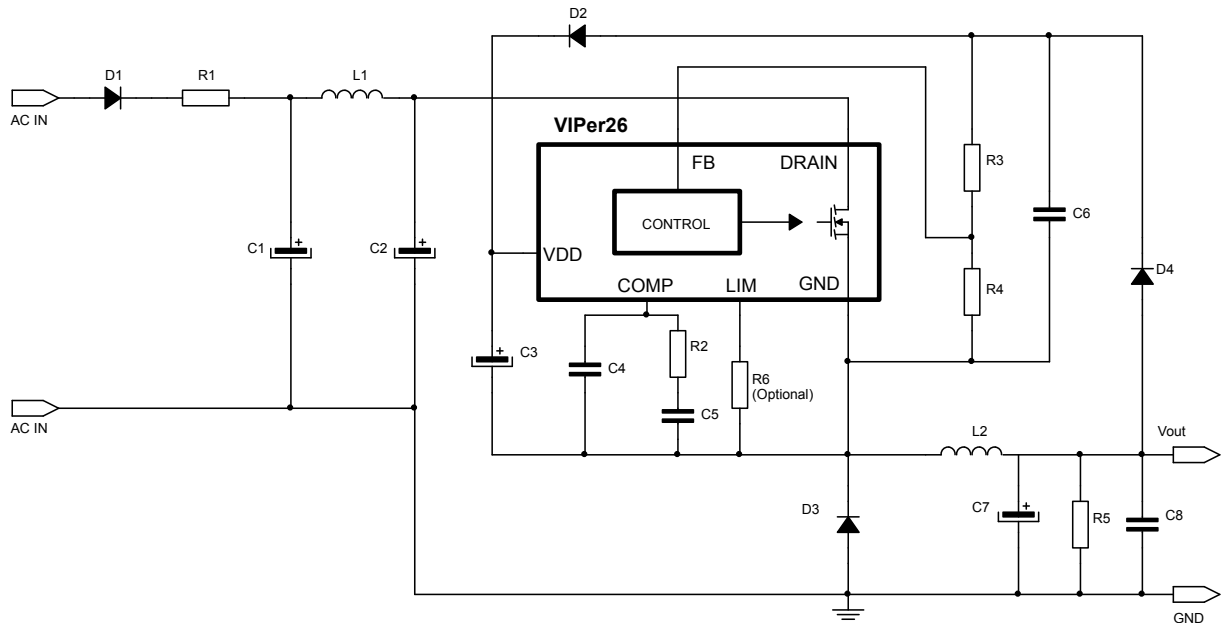
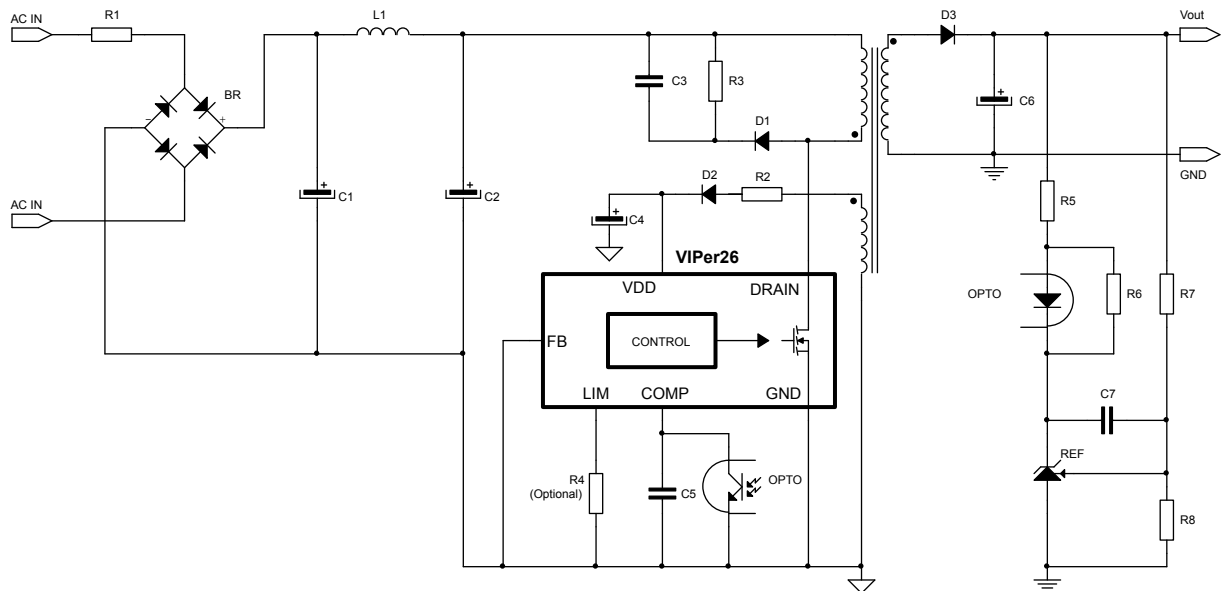


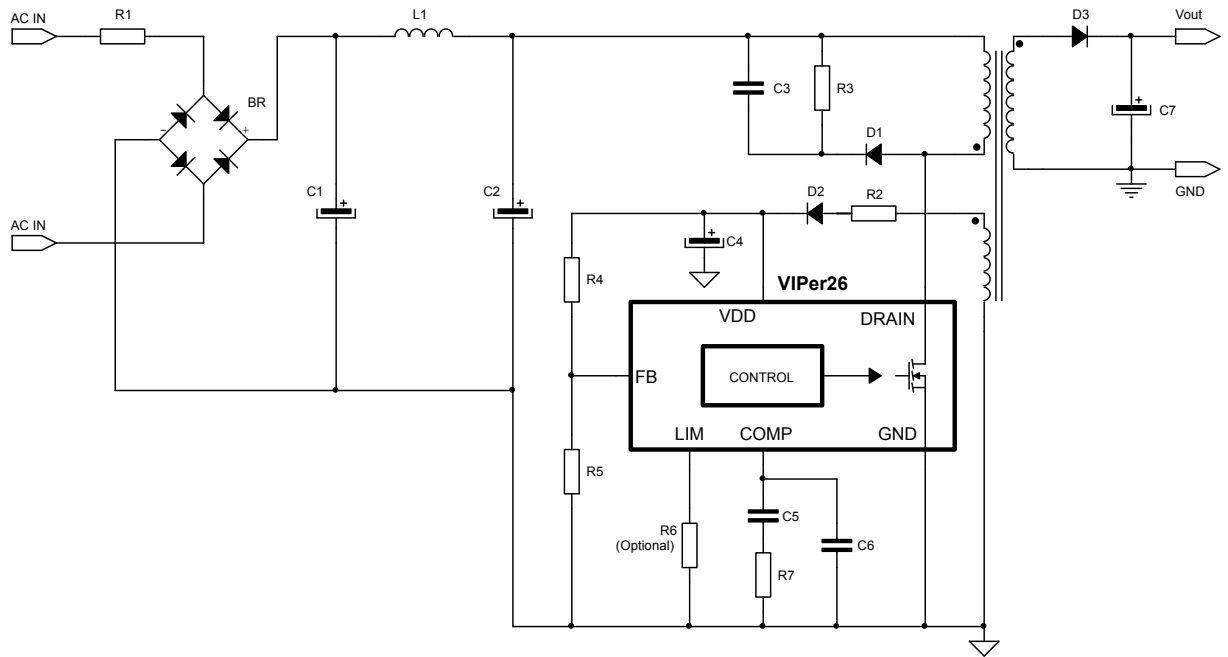
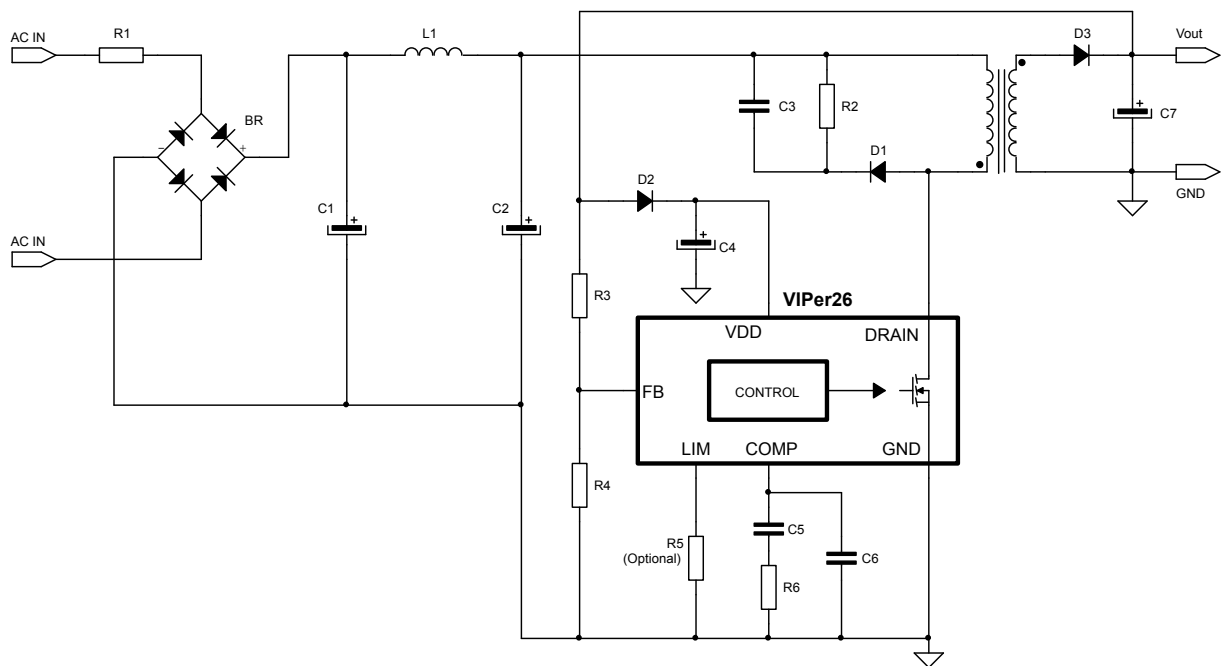
**Figure 15. Power MOSFET capacitance variation vs  $V_{DS}$** 

**Figure 16. SOA SO16N package**

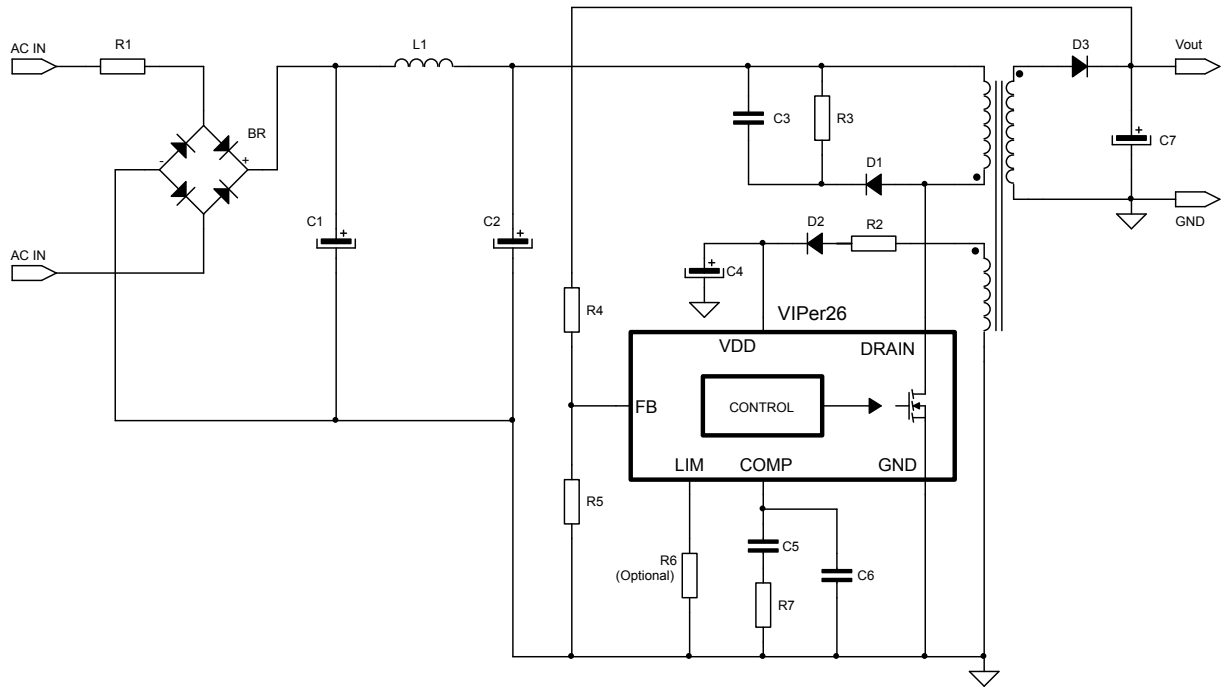
 When mounted on a standard single side FR4 board with 100 mm<sup>2</sup> of Cu (35µm thick)

**Figure 17. SOA DIP7 package**

 When mounted on a standard single side FR4 board with 100 mm<sup>2</sup> of Cu (35µm thick)

**Figure 18. Thermal shutdown**


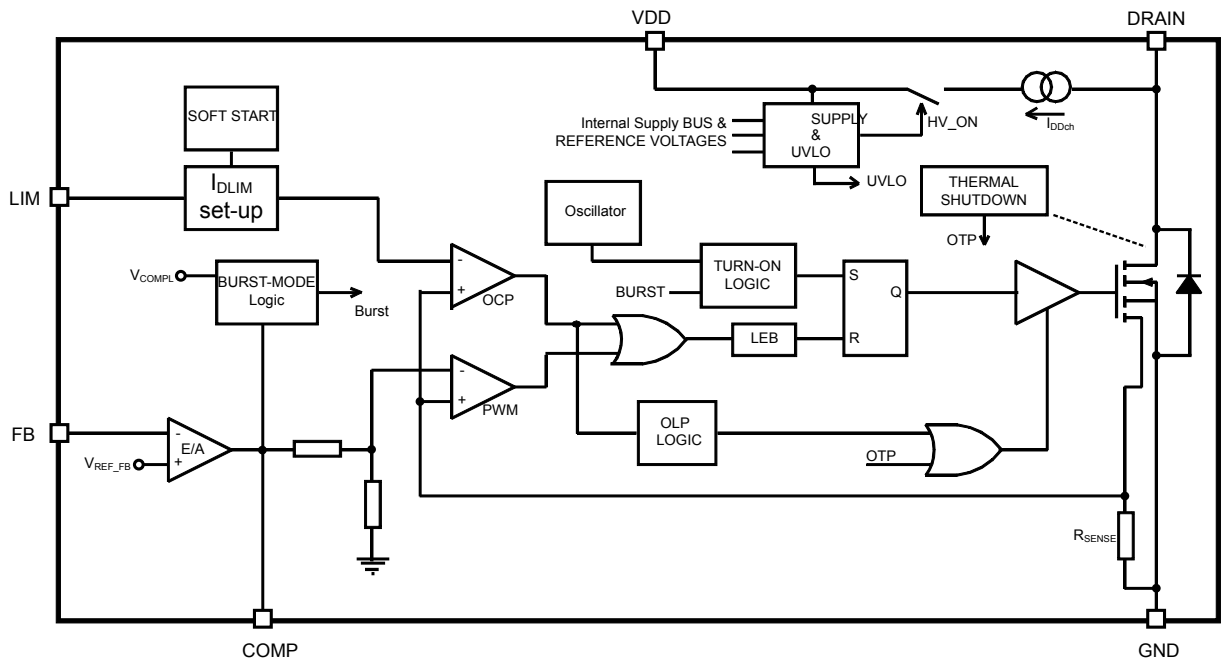
## 4 Typical circuits

**Figure 19. Buck converter ( $V_{OUT} > V_{DDCson}$ )**

**Figure 20. Flyback converter (isolated)**


**Figure 21. Flyback converter (primary regulation)**

**Figure 22. Flyback converter (non isolated,  $V_{OUT} \geq V_{DCCson}$ )**


**Figure 23. Flyback converter (non isolated,  $V_{OUT} < V_{DDCSon}$ )**


## 4.1 Block diagram

**Figure 24. Block diagram**


## 4.2 Typical power

**Table 8. VIPer26 typical power**

230 V <sub>AC</sub>		85-265 V <sub>AC</sub>	
Adapter <sup>(1)</sup>	Open Frame <sup>(2)</sup>	Adapter <sup>(1)</sup>	Open Frame <sup>(2)</sup>
18 W	20 W	10 W	12 W

1. Typical continuous power in non-ventilated enclosed adapter measured at 50°C ambient.
2. Maximum practical continuous power in an open frame design at 50°C ambient, with adequate heat sinking.

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## 5 Power section

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The power section is implemented with an n-channel power MOSFET with a breakdown voltage of 800 V min. and a typical  $R_{DS(on)}$  of 7  $\Omega$ . It includes a SenseFET structure to allow virtually lossless current sensing and a thermal sensor.

The gate driver of the power MOSFET is designed to supply a controlled gate current during turn ON and turn OFF in order to minimize common mode EMI. During UVLO conditions, an internal pull-down circuit holds the gate low in order to ensure that the power MOSFET cannot be turned ON accidentally.

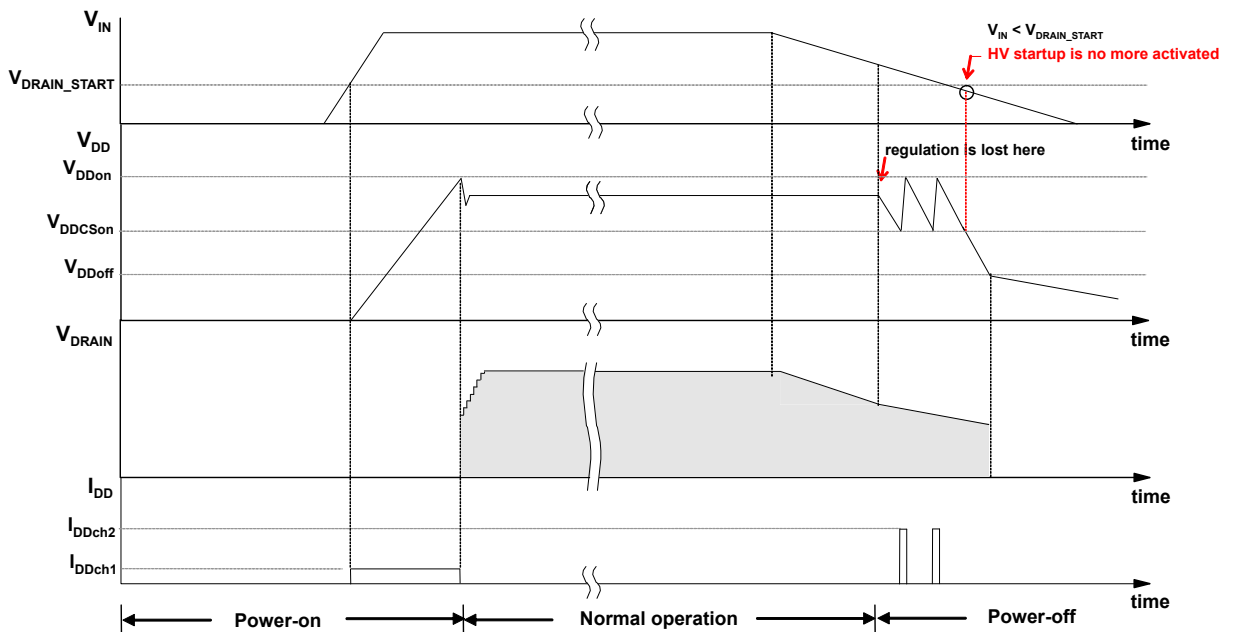
## 6 High-voltage current generator

The high voltage current generator is supplied by the DRAIN pin. On initial startup of the converter, it is enabled when the voltage across the input bulk capacitor reaches the  $V_{DRAIN\_START}$  threshold, sourcing the  $I_{DDch1}$  current (see Table 6. Supply section). As the  $V_{DD}$  voltage reaches the  $V_{DDon}$  start-up threshold, the power section starts switching and the high voltage current generator is turned OFF. The VIPer26 is powered by the external source. After the start-up, the auxiliary winding or the diode connected to the output voltage must power the  $V_{DD}$  capacitor with a voltage higher than the  $V_{DDCSon}$  threshold (see Table 6).

During the switching, the internal current source is disabled and the consumptions are minimized. If a fault occurs, switching is stopped and the device is self biased by the internal high voltage current source; it is activated between the levels  $V_{DDCSon}$  and  $V_{DDon}$  delivering the current  $I_{DDch2}$  to the  $V_{DD}$  capacitor during the MOSFET OFF time, see Figure 25.

At converter power-down, the  $V_{DD}$  voltage drops and the converter activity stops as it falls below the  $V_{DDoff}$  threshold (see Table 6).

Figure 25. Power ON and power OFF



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## 7 Oscillator

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The switching frequency is internally fixed at 60 kHz (VIPER26LN or LD) or 115 kHz (VIPER26HN or HD). In both cases, the switching frequency is modulated by approximately  $\pm 4$  kHz (60 kHz version) or  $\pm 8$  kHz (115 kHz version) at 230 Hz (typical) rate, so that the resulting spread-spectrum action distributes the energy of each harmonic of the switching frequency over a number of sideband harmonics, having the same net energy but with smaller amplitudes.



## 8 Soft startup

During the converter start-up phase, the soft-start function progressively increases the cycle-by-cycle drain current limit, up to the default value  $I_{Dlim}$ . This way, the drain current is further limited and the output voltage is progressively increased, therefore reducing the stress on the secondary diode. The soft-start time is internally fixed to  $t_{SS}$  (see typical value on [Table 7. Controller section](#)) and the function is activated for any converter start-up attempt or a fault event.

This function helps prevent transformer saturation during start-up and short-circuit.

## 9 Adjustable current limit set point

The VIPer26 includes a current mode PWM controller: cycle by cycle the drain current is sensed through the integrated resistor  $R_{SENSE}$  and the voltage is applied to the non inverting input of the PWM comparator, see [Figure 24. Block diagram](#). As soon as the sensed voltage is equal to the voltage derived from the COMP pin, the power MOSFET is switched OFF.

In parallel with the PWM operations, the comparator OCP, see [Figure 24](#), checks the level of the drain current and switch OFF the power MOSFET in case the current is higher than the threshold  $I_{Dlim}$ , see [Table 7. Controller section](#).

The level of the drain current limit,  $I_{Dlim}$ , can be reduced depending on the sunk current from the pin LIM. The resistor  $R_{LIM}$ , between LIM and GND pins, fixes the current sunk and therefore the level of the current limit,  $I_{Dlim}$ , see [Figure 12.  \$I\_{DLIM}\$  vs.  \$R\_{LIM}\$](#) .

When the LIM pin is left open or if the  $R_{LIM}$  has a high value (i.e.,  $> 80\text{ k}\Omega$ ), the current limit is fixed to its default value,  $I_{Dlim}$ , as reported in [Table 7](#).

## 10 FB pin and COMP pin

The device can be used both in non-isolated and in isolated topology. In case of non-isolated topology, the feedback signal from the output voltage is applied directly to the FB pin as inverting input of the internal error amplifier with reference voltage,  $V_{REF\_FB}$ , see [Table 7. Controller section](#).

The output of the error amplifier sources and sinks the current,  $I_{COMP}$ , to and from the compensation network connected on the COMP pin. This signal is then compared in the PWM comparator with the signal coming from the SenseFET; the power MOSFET is switched off when the two values are the same on a cycle by cycle basis. See [Figure 24. Block diagram](#) and [Figure 26. Feedback circuit](#).

When the power supply output voltage is equal to the error amplifier reference voltage,  $V_{REF\_FB}$ , a single resistor has to be connected from the output to the FB pin. For higher output voltages, the external resistor divider is needed. If the voltage on FB pin is accidentally left floating, an internal pull-up protects the controller.

The output of the error amplifier is externally accessible through the COMP pin and it is used for the loop compensation: usually an RC network.

As shown in [Figure 26](#), the internal error amplifier has to be disabled in isolated power supplies (FB pin shorted to GND). In this case, an internal resistor is connected between an internal reference voltage and the COMP pin, see [Figure 26](#). The current loop has to be closed on the COMP pin through the opto-transistor in parallel with the compensation network. The  $V_{COMP}$  dynamic range is between  $V_{COMPL}$  and  $V_{COMPH}$ , as shown in [Figure 27](#).

When the voltage  $V_{COMP}$  drops below the voltage threshold  $V_{COMPL}$ , the converter enters burst mode, see [Section 11 Burst mode](#).

When the voltage  $V_{COMP}$  rises above the  $V_{COMPH}$  threshold, the peak drain current will reach its limit, as well as the deliverable output power.

**Figure 26. Feedback circuit**

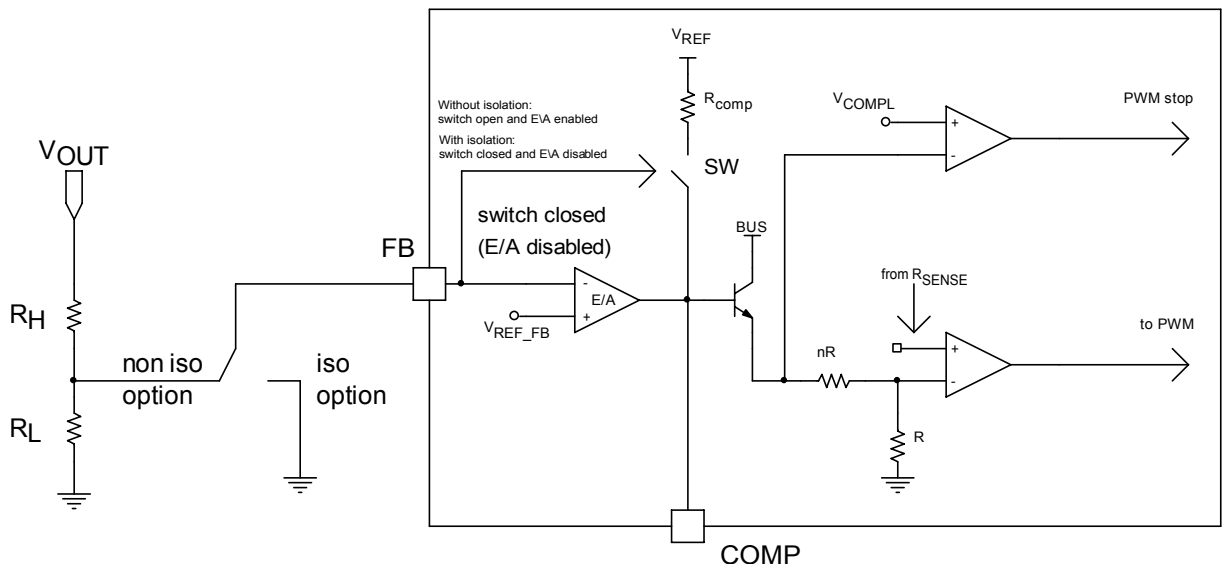
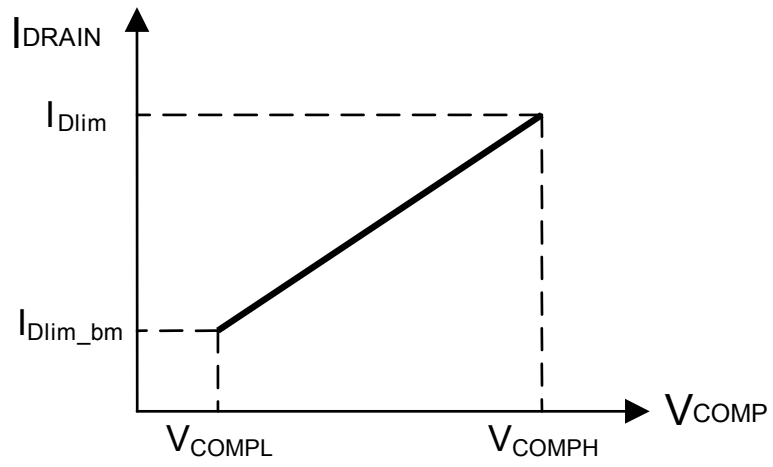


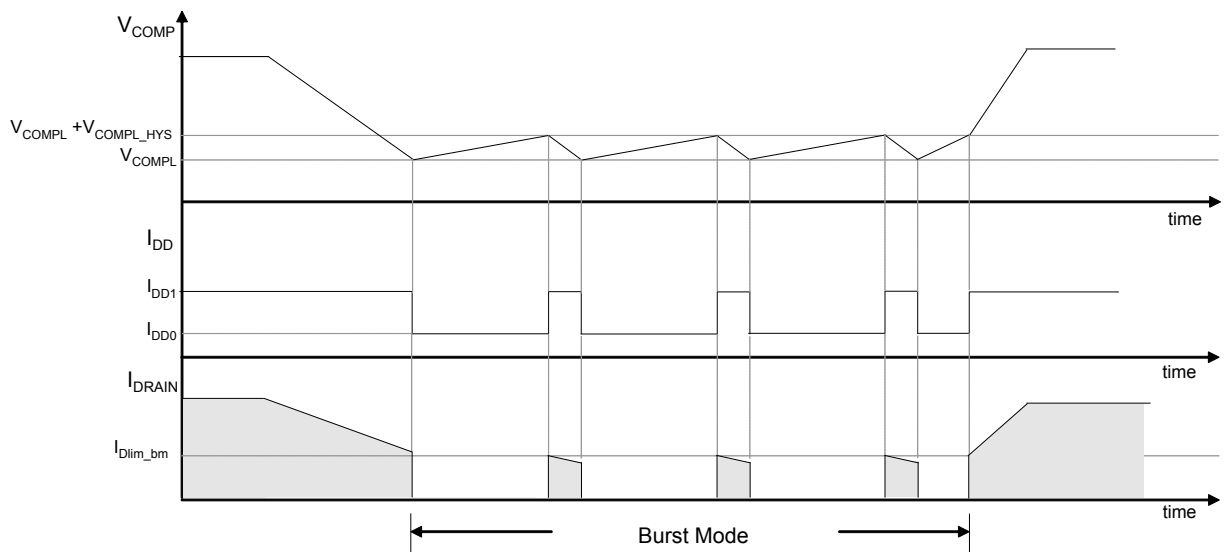
Figure 27. COMP pin voltage versus  $I_{DLIM}$



## 11 Burst mode

When the voltage  $V_{COMP}$  drops below the threshold,  $V_{COMPL}$ , the power MOSFET is kept in the OFF state and the consumption is reduced to  $I_{DD0}$  current, as given in Table 6. Supply section. In reaction to the energy delivery interruption, the  $V_{COMP}$  voltage increases and, as soon as it exceeds the threshold  $V_{COMPL} + V_{COMPL\_HYS}$ , the converter starts switching again with consumption level equal to  $I_{DD1}$  current. This ON-OFF operation mode, referred to as “burst mode” (see Figure 28), reduces the average frequency, which can fall down even to a few hundreds hertz, thus minimizing all frequency-related losses and making it easier to comply with energy saving regulations. During burst mode, the drain current limit is reduced to the value  $I_{Dim\_bm}$  (given in Table 7. Controller section) in order to avoid audible noise issues.

**Figure 28. Load-dependent operating modes: timing diagrams**



## 12 Automatic restart after overload or short-circuit

The overload protection is implemented automatically through the integrated up-down counter. Every cycle, it is incremented or decremented depending on whether the current logic detects the limit condition or not. The limit condition is the peak drain current,  $I_{Dlim}$  given in Table 7. Controller section, or the one set by the user through the  $R_{LIM}$  resistor, as shown in Figure 12.  $I_{DLIM}$  vs.  $R_{LIM}$ .

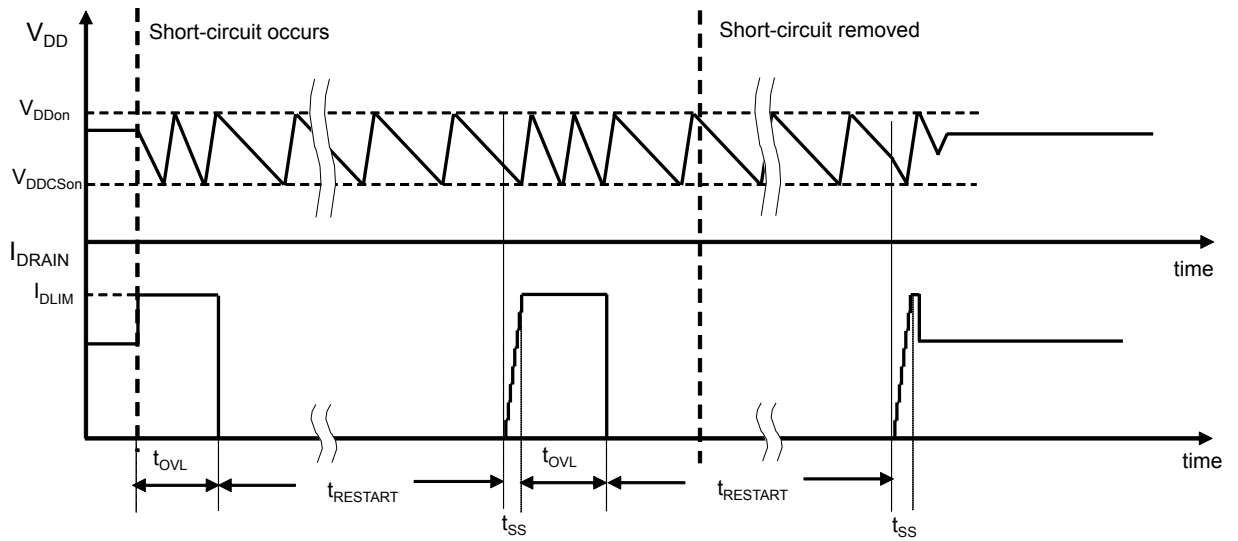
After the reset of the counter, if the peak drain current is continuously equal to the level  $I_{Dlim}$ , the counter will be incremented until the fixed time,  $t_{OVL}$ , after which the power MOSFET switch ON is disabled. It is activated again, through the soft start, after the  $t_{RESTART}$  time, see Figure 29. Timing diagram: OLP sequence and the relevant time values in Table 7.

In case of an overload or short-circuit event, the power MOSFET switching is stopped after a time that depends on the counter and whose maximum can equal  $t_{OVL}$ . The protection occurs in the same way until the overload condition is removed, see Figure 29.

This protection ensures restart attempts of the converter with low repetition rate, so that it works safely with extremely low power throughput and avoids IC overheating in case of repeated overload events.

If the overload is removed before the protection tripping, the counter will be decremented cycle by cycle down to zero and the IC will not be stopped.

**Figure 29. Timing diagram: OLP sequence**



## 13 Open loop failure protection

If the power supply is built in fly-back topology and the VIPer26 is supplied by an auxiliary winding, as shown in Figure 30. FB pin connection for non-isolated flyback and Figure 31. FB pin connection for isolated flyback, the converter is protected against feedback loop failure or accidental disconnections of the winding.

Regarding the Figure 30 and Figure 31 schematics for non-isolated flyback and isolated flyback, if  $R_H$  is opened or  $R_L$  is shorted, the VIPer26 works at its drain current limitation. The output voltage,  $V_{OUT}$ , will increase and so will the auxiliary voltage,  $V_{AUX}$ , which is coupled with the output according to the secondary-to-auxiliary turns ratio.

As the auxiliary voltage increases up to the internal  $V_{DD}$  active clamp,  $V_{DDclamp}$  (value given in Table 7. Controller section) and the clamp current injected on  $V_{DD}$  pin exceeds the open loop failure current threshold,  $I_{DDol}$  (value given in Table 7), a fault signal is internally generated.

In order to distinguish an actual malfunction from a bad auxiliary winding design, both the above conditions (drain current equal to the drain current limitation and  $V_{DD}$  current higher than  $I_{DDol}$  through  $V_{DD}$  clamp) have to be verified to reveal the fault.

If  $R_L$  is opened or  $R_H$  is shorted, the output voltage,  $V_{OUT}$ , will be clamped to the reference voltage  $V_{REF\_FB}$  in case of non isolated flyback or to the external  $T_L$  voltage reference in case of isolated flyback).

**Figure 30. FB pin connection for non-isolated flyback**

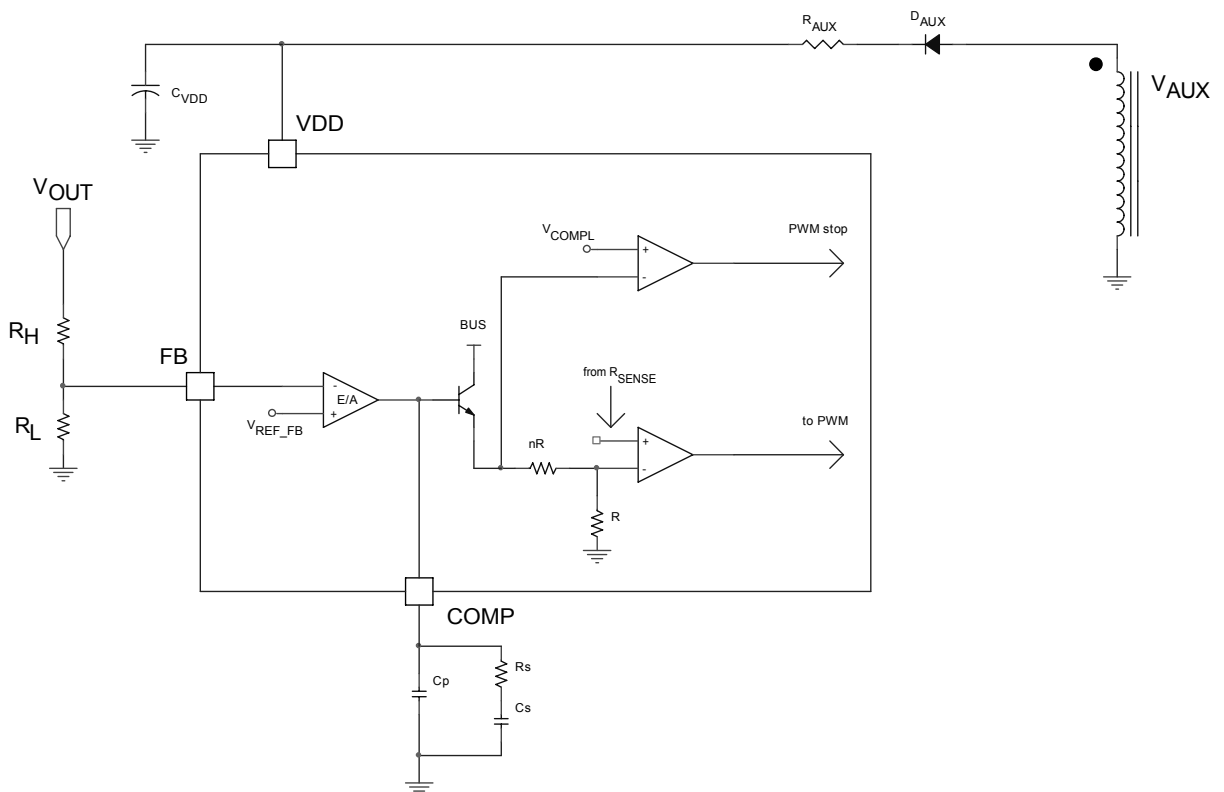
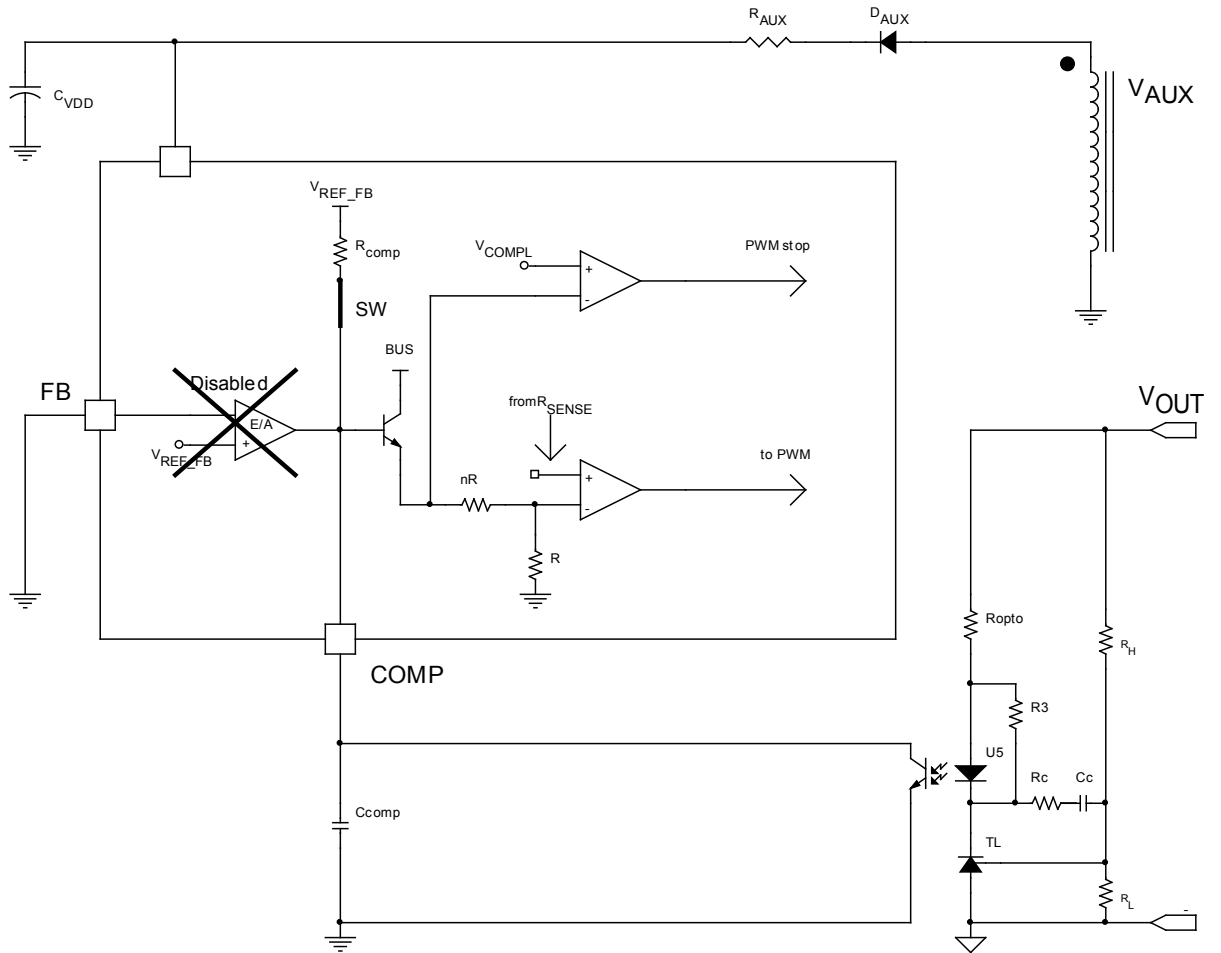


Figure 31. FB pin connection for isolated fly-back



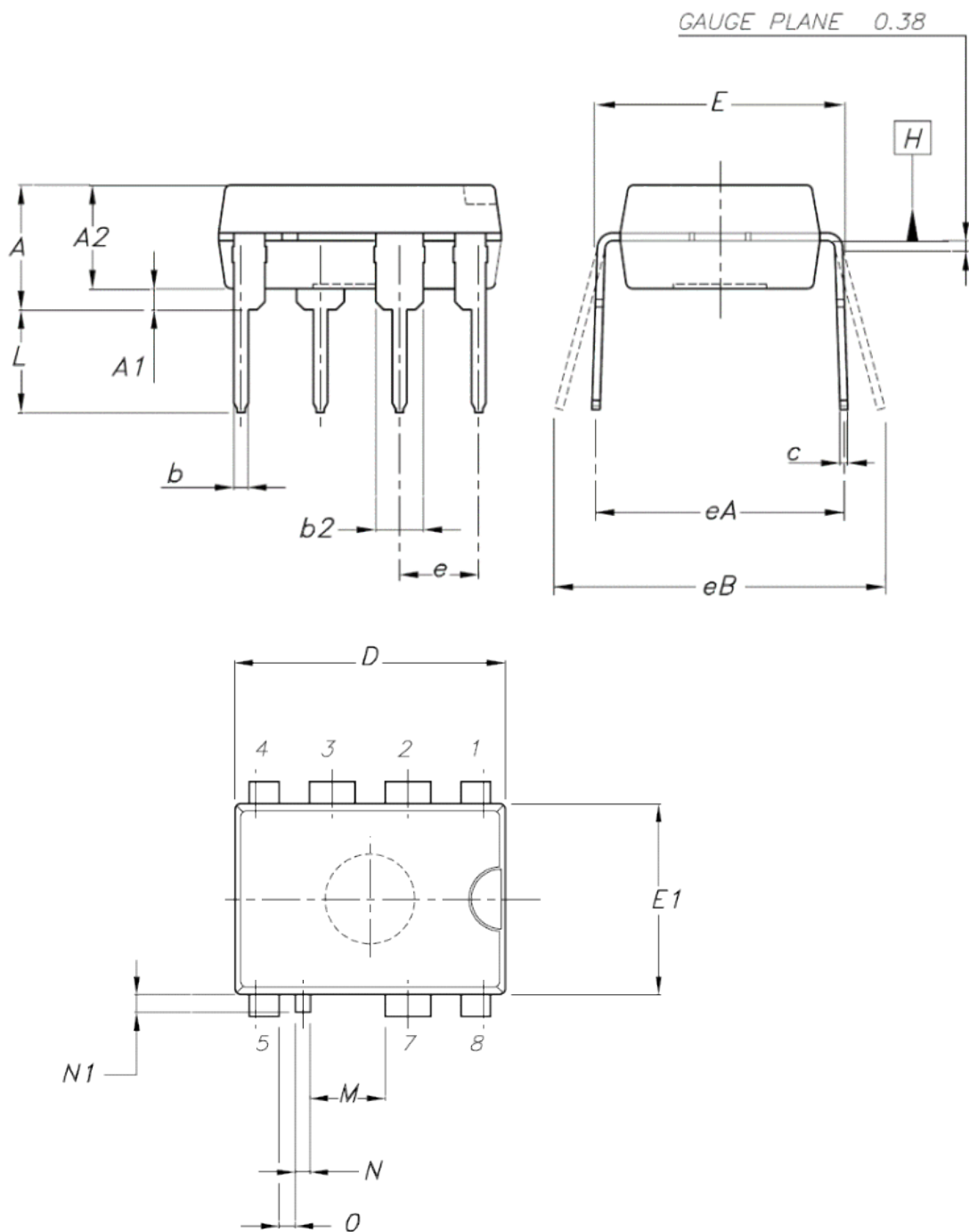


## 14 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 14.1 DIP-7 package information

Figure 32. DIP-7 package outline



**Table 9. DIP-7 package mechanical data**

Dim.	mm			Notes
	Min.	Typ.	Max.	
A	-	-	5.33	-
A1	0.38	-	-	-
A2	2.92	3.30	4.95	-
b	0.36	0.46	0.56	-
b2	1.14	1.52	1.78	-
c	0.20	0.25	0.36	-
D	9.02	9.27	10.16	-
E	7.62	7.87	8.26	-
E1	6.10	6.35	7.11	-
e	-	2.54	-	-
eA	-	7.62	-	-
eB	-	-	10.92	-
L	2.92	3.30	3.81	-
M	-	2.508	-	6 - 8
N	0.40	0.50	0.60	-
N1	-	-	0.60	-
O	-	0.548	-	7 - 8

## 14.2 SO16 narrow package information

Figure 33. SO16 narrow package outline

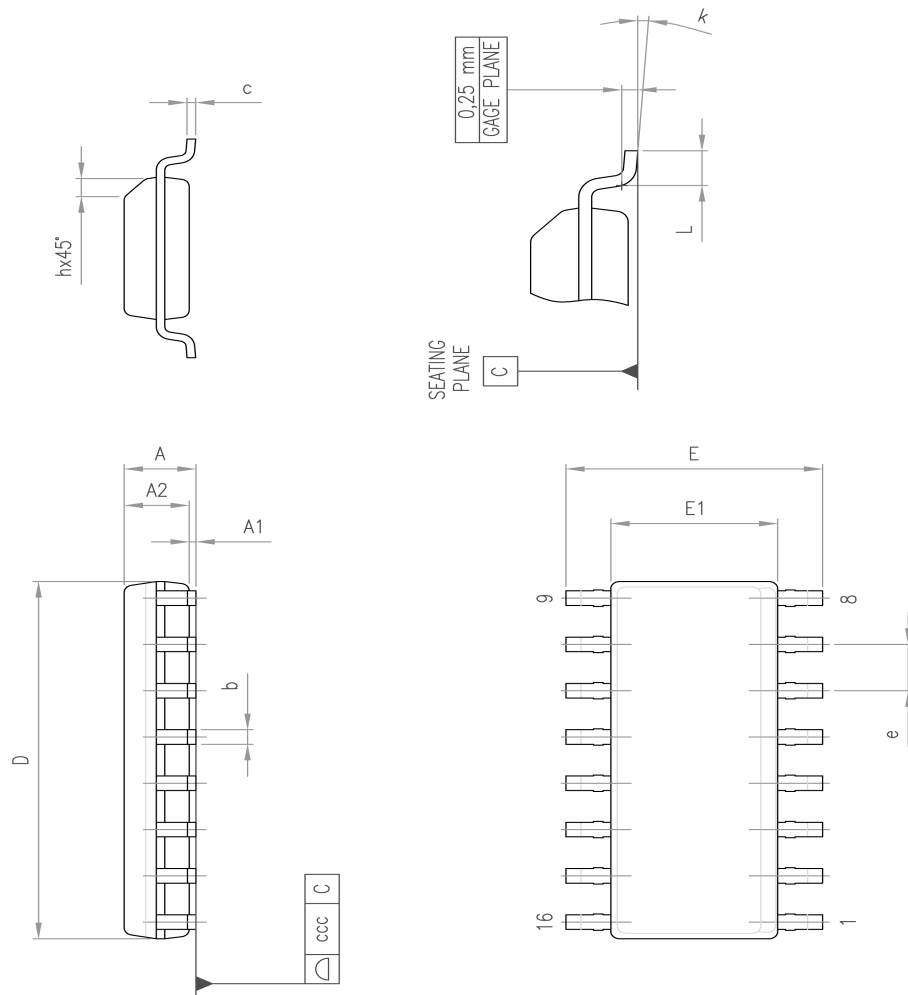


Table 10. SO16 narrow mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A			1.75
A1	0.1		0.25
A2	1.25		
b	0.31		0.51
c	0.17		0.25
D	9.8	9.9	10
E	5.8	6	6.2
E1	3.8	3.9	4
e		1.27	
h	0.25		0.5
L	0.4		1.27
k	0		8
ccc			0.1

## 15 Order code

**Table 11. Order code**

Order code	Package	Packing
VIPER26LN	DIP-7	Tube
VIPER26HN		
VIPER26HD	SO16N	Tube
VIPER26HDTR		Tape and reel
VIPER26LD		Tube
VIPER26LDTR		Tape and reel

## Revision history

**Table 12. Document revision history**

Date	Version	Changes
26-Aug-2010	1	Initial release.
01-Sep-2010	2	Updated Figure 30 on page 23.
11-Oct-2020	3	Throughout document: <ul style="list-style-type: none"> <li>- updated document template</li> <li>- general reorganisation of sections</li> <li>- minor text edits</li> </ul> On cover page: <ul style="list-style-type: none"> <li>- updated <a href="#">Features and Description</a></li> <li>- added Product status link and Product label</li> </ul> In <a href="#">Section 1 Pin settings</a> : <ul style="list-style-type: none"> <li>- updated <a href="#">Table 1. Pin descriptions</a></li> </ul> In <a href="#">Section 2 Electrical and thermal ratings</a> : <ul style="list-style-type: none"> <li>- updated <a href="#">Table 3. Thermal data</a></li> <li>- added <a href="#">Figure 2. R<sub>th</sub> versus area</a> and <a href="#">Table 4. Avalanche characteristics</a></li> </ul> In <a href="#">Table 6. Supply section</a> : <ul style="list-style-type: none"> <li>- updated <a href="#">V<sub>DRAIN_START</sub></a> and <a href="#">I<sub>DD1</sub> Max. values</a></li> </ul> In <a href="#">Section 3 Typical electrical characteristics</a> : <ul style="list-style-type: none"> <li>- added <a href="#">Figure 16. SOA SO16N package</a> and <a href="#">Figure 17. SOA DIP7 package</a></li> </ul> In <a href="#">Section 4 Typical circuits</a> : <ul style="list-style-type: none"> <li>- updated all figures</li> </ul>

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